NSN 5961-01-487-8164

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-487-8164 **Inclosure Material:** Metal **Overall Length:** Between 0.130 inches and 0.146 inches **Overall Diameter:** Between 0.063 inches and 0.067 inches **End Application:** Joint stars target radar system **Mounting Method:** Terminal **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 270.0 nonrepetitive peak reverse voltage and 225.0 working peak reverse voltage **Current Rating Per Characteristic:** 5.00 amperes forward current, average preset **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**